





# IFP44 P-Channel JFET

#### Features

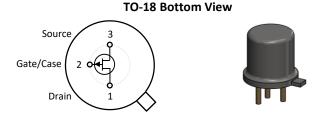
- InterFET P0099F Geometry
- Low Noise: 8 nV/VHz Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

#### Applications

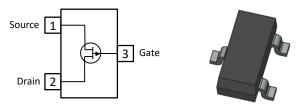
• Replacement for Japanese 2SJ44

### Description

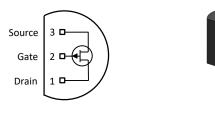
The 25V InterFET IFP44 is a replacement for the Japanese 2SJ44. Targeted for switching and commutator designs. The on resistance is typically less than 100 Ohms at room temperatures. The TO-18 package is hermetically sealed and suitable for military applications.







**TO-92 Bottom View** 



#### **Product Summary**

Parameters		IFP44 Min	Unit	
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage	25	V	
IDSS	Drain to Source Saturation Current	1	mA	
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	0.2	V	
GFS	Forward Transconductance	9	mS	

#### Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
IFP44	Through-Hole	TO-18	Bulk
PN44	Through-Hole	TO-92	Bulk
SMP44	Surface Mount	SOT23	Bulk
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMP44TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
IFP44COT	Chip Orientated Tray (COT Waffle Pack)	СОТ	400/Waffle Pack
IFP44CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



**Disclaimer:** It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.







## **Electrical Characteristics**

## Maximum Ratings (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
VRGS	Reverse Gate Source and Gate Drain Voltage	25	V
$I_{FG}$	Continuous Forward Gate Current	10	mA
PD	Continuous Device Power Dissipation	300	mW
Р	Power Derating	2.8	mW/°C
Τı	Operating Junction Temperature	-55 to 125	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

### Static Characteristics (@ TA = 25°C, Unless otherwise specified)

			IFP44		
	Parameters	Conditions	Min	Max	Unit
V(BR)GSS	Gate to Source Breakdown Voltage	V <sub>DS</sub> = 0V, I <sub>G</sub> = -1µA	25		V
IGSS	Gate to Source Reverse Current	$V_{GS} = 10V, V_{DS} = 0V$		1	nA
V <sub>GS(OFF)</sub>	Gate to Source Cutoff Voltage	V <sub>DS</sub> = 10V, I <sub>D</sub> = 100nA	0.2	1.5	V
I <sub>DSS</sub>	Drain to Source Saturation Current	$V_{GS} = 0V, V_{DS} = 10V$ (Pulsed)	1	18	mA

### Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

			IFP44	
	Parameters	Conditions	Typical	Unit
GFS	Forward Transconductance	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V, f = 1kHz	9	mS
C <sub>iss</sub>	Input Capacitance	$V_{DS}$ = 10V, $V_{GS}$ = 0V, f = 1MHz	15	pF
Crss	Reverse Transfer Capacitance	V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V, f = 1MHz	3	pF



Technical

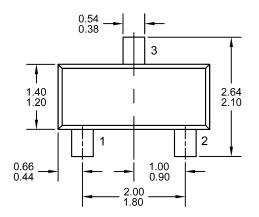
Support

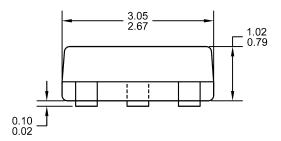
Order

Now

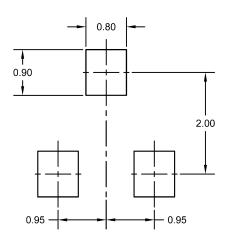
## SOT23 (TO-236AB) Mechanical and Layout Data

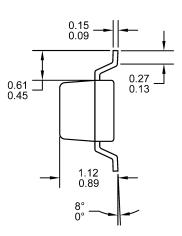
### **Package Outline Data**





### Suggested Pad Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- 5. Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.

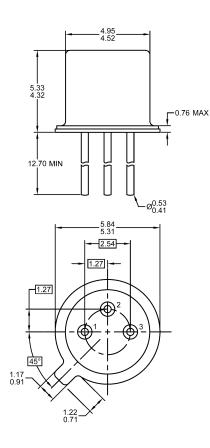




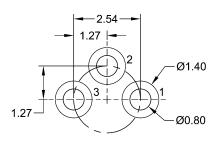
# IFP44

## **TO-18 Mechanical and Layout Data**

### **Package Outline Data**



### Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.29 grams
- 3. Bulk product is shipped in standard ESD shipping material
- 4. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.